

# Asymmetry of the Stokes and anti-Stokes components of the nonlinear response of high-temperature superconductors in the method of picosecond biharmonic pumping

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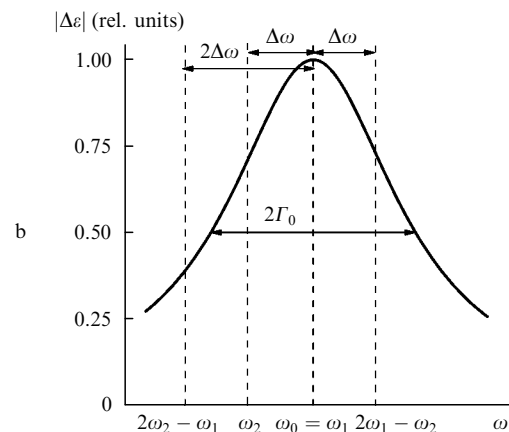
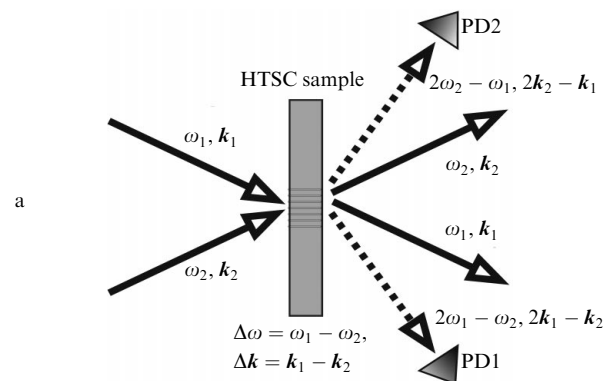
**Abstract.** It is shown in the model of the nonlinear response of high-temperature superconductors (HTSCs) caused by interband transitions in the electronic spectrum with a metastable energy gap that the Stokes and anti-Stokes components of the HTSC response to picosecond biharmonic pumping are asymmetric, and for the excitation-pulse frequency detuning exceeding  $100 \text{ cm}^{-1}$ , the efficiency of self-diffraction in the directions corresponding to these two components is different.

**Keywords:** nonlinear response of high-temperature superconductors, picosecond biharmonic pumping, efficiency of the Stokes and anti-Stokes components of self-diffraction.

## 1. Introduction

In [1–5], the spectral, temporal, and temperature properties of the nonlinear response of high-temperature superconductors (HTSCs) observed at different excitation levels by different methods of femtosecond and picosecond spectroscopy [6–17] were interpreted within the framework of a model based on two assumptions. It was assumed that the energy gap in the electronic spectrum of a HTSC is metastable [18] and the electronic part of the nonlinear response is caused by interband transitions [12, 19–26]. It was shown, in particular, in [4, 5] that the characteristic dip in the dependence of the self-diffraction efficiency  $\eta$  (generation of the field at frequency  $2\omega_1 - \omega_2$ ) on the detuning  $\Delta\omega = \omega_1 - \omega_2$  of the frequencies  $\omega_{1,2}$  of components of picosecond biharmonic pumping (BP) (Fig. 1a), which was observed near the point  $T_0 \simeq T_c$  (transition to the superconducting state) in [7, 9, 10], makes it possible to measure the dependence of the gap width  $\Delta$  on the initial temperature  $T_0$  of a sample.

In the absence of the frequency degeneracy ( $\Delta\omega \neq 0$ , the BP method), the model proposed in [4, 5] admits the appearance of a certain asymmetry of the nonlinear response, i.e. the different dependences  $\eta(\Delta\omega, T_0)$  for two different directions ( $2\mathbf{k}_{1,2} - \mathbf{k}_{2,1}$ ) and frequencies ( $2\omega_{1,2} - \omega_{2,1}$ ) of the self-diffraction signal (Fig. 1a), where  $\mathbf{k}_{1,2}$  are



**Figure 1.** Interaction of pump components at frequencies  $\omega_{1,2}$  with the wave vectors  $\mathbf{k}_{1,2}$ : self-diffraction signals at frequencies  $2\omega_{1,2} - \omega_{2,1}$  detected with photodetectors PD1,2 in directions  $2\mathbf{k}_{1,2} - \mathbf{k}_{2,1}$  (a) and shifts of frequencies  $\omega_{1,2}$  and  $2\omega_{1,2} - \omega_{2,1}$  with respect to the one-photon resonance singularity at  $|\Delta\varepsilon|$  of width  $\Gamma_0$  caused by the frequency detuning  $\Delta\omega = \omega_1 - \omega_2$  (b).

the wave vectors of the BP components. The asymmetry appears because the electronic part of the dependence  $\Delta\varepsilon(\omega)$  has spectral singularities [6, 12] caused by one-photon interband resonances [1–5]. Here,  $\Delta\varepsilon(\omega) = \varepsilon(\omega; E_c^F, T_c) - \varepsilon(\omega; E_0^F, T_0)$  is the change in the dielectric constant  $\varepsilon$  of a sample at frequency  $\omega$  caused by the deviation of the Fermi level  $E_c^F$  and the electron temperature  $T_c$  from their equilibrium values  $E_0^F$  and  $T_0$ , respectively. This is illustrated qualitatively in Fig. 1b, which shows the asymmetry of positions of the frequencies  $\omega_{1,2}$  and  $2\omega_{1,2} - \omega_{2,1}$  of interacting waves on the axis  $\omega$  (for  $\Delta\omega \neq 0$ ) with respect to the point  $\omega_0 = \omega_1$  of the one-photon resonance of width  $\Gamma_0$ . Below, according to the adopted terminology, we will call the

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components of the nonlinear response at frequencies  $2\omega_2 - \omega_1$  and  $2\omega_1 - \omega_2$  the Stokes and anti-Stokes components (see Fig. 1b). Note that the asymmetry of these components was observed earlier in picosecond BP experiments with thin narrow-gap  $\text{PrBa}_2\text{Cu}_3\text{O}_{7-\delta}$  semiconductor films [27].

By using the kinetics  $E_e^F(t)$  and  $T_e(t)$  calculated in [3, 5] and the model of the nonlinear HTSC response in the BP method described in [4, 5], we will show below that this asymmetry does exist when the pump pulses are made coincident in time  $t$ , but only in the region of large frequency detunings ( $\Delta\omega > 100 \text{ cm}^{-1}$ ).

## 2. Nonlinear response model

The self-diffraction process was described by using the model of the coherent four-photon response developed in [4, 5]. It is assumed that the total cubic nonlinear susceptibility of a HTSC sample includes several components [28]:

$$\chi = \chi_{\text{nr}} + \chi_r + \chi_s + \chi_0. \quad (1)$$

Here,  $\chi_{\text{nr}}$  and  $\chi_r$  are the nonresonance and resonance (see [4, 5]) components of the electronic nonlinear response caused by direct and indirect interband transitions;  $\chi_s$  is the component related to excitation of acoustic phonons; and  $\chi_0$  is a constant caused by the errors of the model. The calculation of contributions of these components to  $\chi$  for the anti-Stokes component of the response at frequency  $2\omega_1 - \omega_2$  completely repeats procedures described in detail in [5], and therefore we will not consider it here.

The value of  $\chi_{\text{nr}}$  for the Stokes component at frequency  $2\omega_2 - \omega_1$  was calculated similarly; however, the replacement  $\omega_1 \rightarrow \omega_2 = \omega_1 + \Delta\omega$  was made in the resonance denominators of  $P_0$  and  $P_{\pm}$  [in expressions (58) and (59) in [5]]. In this case, the Raman resonance frequency  $\Delta\omega$  in denominators of  $K_{\pm}$  [expression (60) in [5]] did not change, of course. The one-photon resonance frequencies in  $P_0$  and  $P_{\pm}$  were found by interpolating the same data [29] for the band structure [the electronic energy  $E_i(\mathbf{k}_e)$  in the  $(i, \mathbf{k}_e)$  state, where  $i$  numerates the electronic bands and  $\mathbf{k}_e$  is the quasi-momentum] of  $\text{La}_2\text{CuO}_4$  at room temperature taking into account the symmetry and periodicity requirements [30]. The cooling of a HTSC sample was simulated by the same substitution  $E_i(\mathbf{k}_e) \rightarrow E_0^F \pm \{[E_i(\mathbf{k}_e) - E_0^F]^2 + \Delta^2(T_0)\}^{1/2}$  for  $E_i(\mathbf{k}_e) > E_0^F$  and  $E_i(\mathbf{k}_e) < E_0^F$ , respectively, describing the redistribution of the density of states near the Fermi surface upon the phase transition. The energy gap width

$$\Delta(T_0) = \begin{cases} 3.12k_B T_c (1 - T_0/T_c)^{1/2} & \text{for } T_0 \leq T_c, \\ 0 & \text{for } T_0 > T_c \end{cases} \quad (2)$$

was assumed a constant depending only on  $T_0$  and  $T_c$  ('frozen' [18] gap of the s symmetry in the weak coupling approximation of the BCS theory [31]). Here,  $k_B$  is the Boltzmann constant. The bands lying in the range  $|E_i(\mathbf{k}_e) \pm E_0^F| \leq 2.5 \text{ eV}$  were taken into account. As in [4, 5],  $\chi_r$  was calculated by using the model of the effective two-level system, and  $\chi_s$  – from the traditional relation for the Mandelstam–Brillouin nonlinearity [28] convoluted with the spectrum of BP components of width  $\delta\omega = 1.5 \text{ cm}^{-1}$  [8, 9] taking into account the low sound decay velocity.

It was assumed in numerical calculations that both of the BP components at the point  $\Delta\omega = 0$  had wavelengths  $\lambda_0 = 625, 630, \text{ and } 650 \text{ nm}$ . As in [3, 5], we simulated the situation with BP pulses of duration  $\tau_p = 20 \text{ ps}$  (the values of  $E_e^F$  and  $T_e$  averaged over  $\tau_p$  were used) incident simultaneously on a  $\sim 200\text{-nm}$ -thick  $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$  film ( $T_c = 91 \text{ K}$ ) on a  $\text{SrTiO}_3$  substrate absorbing 30% of the total energy  $4 \times 10^{-7} \text{ J}$  of pump pulses focused into a spot of diameter  $150 \mu\text{m}$  [7, 9, 10]. The values of all free parameters of the model corresponded to those used in [5], i.e. the relative amplitudes of the components  $\chi_r, \chi_s,$  and  $\chi_0$  were specified so that the dependence  $\eta(\Delta\omega, T_0) \propto |\chi(\Delta\omega, T_0)|^2$  for the anti-Stokes component of the nonlinear response for  $\lambda_0 = 625 \text{ nm}$  corresponded to experimental data [9], i.e. had dips at points  $\Delta\omega = 10$  and  $63 \text{ cm}^{-1}$  for  $T_0 = 90$  and  $80 \text{ K}$ . The polarisation relaxation rates used in calculations of  $\chi_{\text{nr}}$  and  $\chi_r$  were  $\Gamma = 150$  and  $50 \text{ cm}^{-1}$ , as in [4, 5], which provided good agreement between the calculated and experimental widths of  $\Delta\varepsilon(\omega)$  spectral features [6, 12].

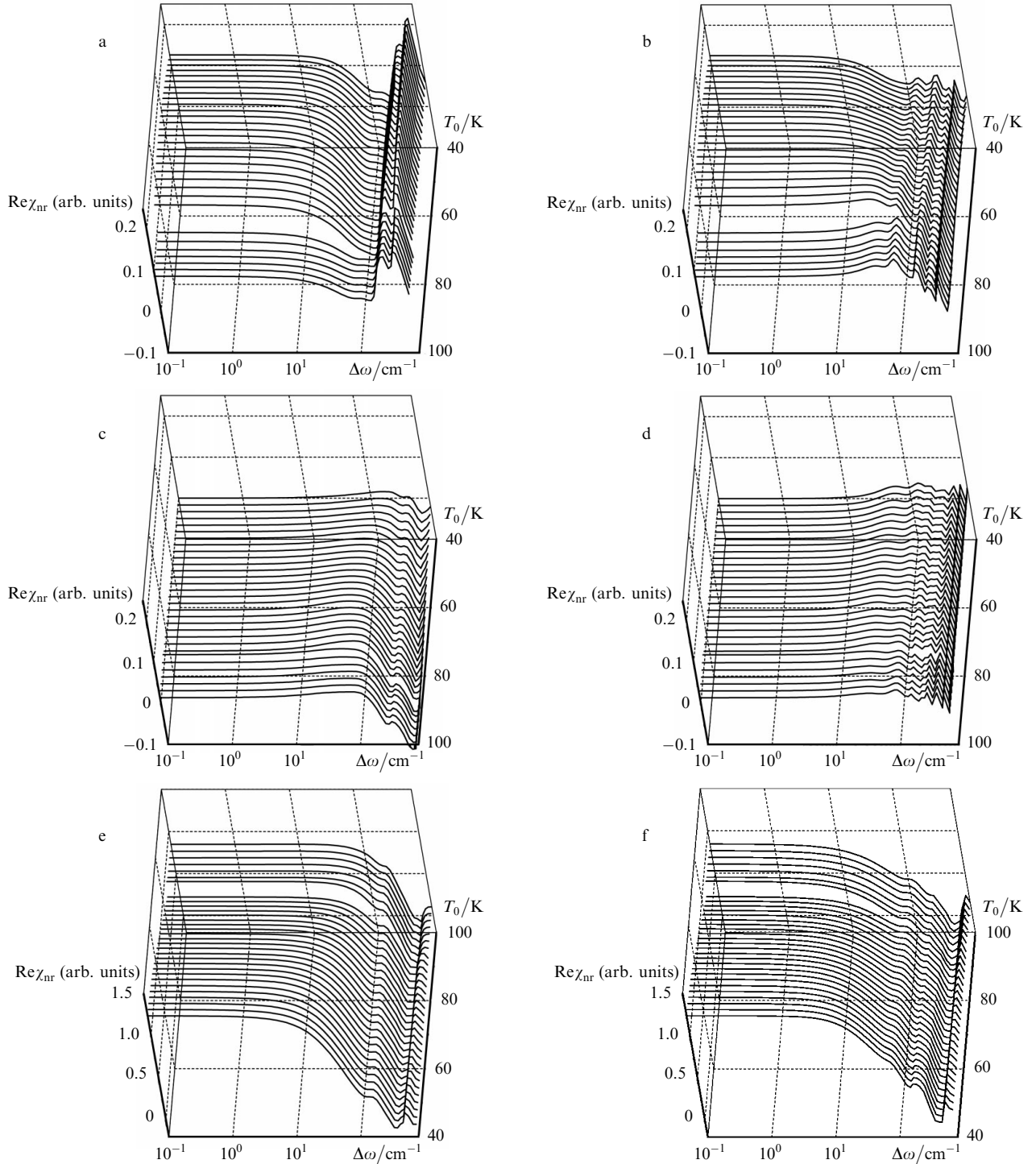
## 3. Results of simulations

Figures 2 and 3 show variations in the real (Re) and imaginary (Im) parts of  $\chi_{\text{nr}}$  in the plane  $(\Delta\omega, T_0)$  for the anti-Stokes and Stokes components of the nonlinear response and the BP components with coincident frequencies at points  $\lambda_0 = 625, 630, \text{ and } 650 \text{ nm}$ . It is easy to verify that the dependences  $\chi_{\text{nr}}(\Delta\omega)$  for the response components at frequencies  $2\omega_2 - \omega_1$  and  $2\omega_1 - \omega_2$  are identical in the frequency detuning range  $\Delta\omega < 100 \text{ cm}^{-1}$  for all values of  $T_0$  and  $\lambda_0$ . And only for  $\Delta\omega > 100 \text{ cm}^{-1}$ , the asymmetry appears, which is especially noticeable for the imaginary part of  $\chi_{\text{nr}}$  (Fig. 3) and increases with increasing  $\Delta\omega$ . At first glance, taking into account the value  $\Gamma = 150 \text{ cm}^{-1}$  used in calculations, this result seems quite obvious. However, this is not exactly so, because we are dealing here with integral relations describing  $\chi_{\text{nr}}(\Delta\omega)$ , in which even a weak asymmetry of many interfering terms can cause a strong asymmetry of the result of interference.

The dependences  $\chi_r(\Delta\omega, T_0)$  and  $\chi_s(\Delta\omega, T_0)$  are not presented here because they do not change with  $\lambda_0$ , are symmetric with respect to the replacement  $\omega_1 \leftrightarrow \omega_2$ , and simply repeat dependences presented in [5]. In principle, this is not surprising because the models used to describe the contributions of these components of the nonlinear response have a symmetric structure.

Figure 4 shows the calculated dependences of the modulus of the nonlinear response  $|\chi(\Delta\omega, T_0)|$  for the anti-Stokes and Stokes components at the same frequency-coincidence points  $\lambda_0 = 625, 630, \text{ and } 650 \text{ nm}$ . It is reasonable that dependences  $|\chi(\Delta\omega)|$  for the response components at frequencies  $2\omega_2 - \omega_1$  and  $2\omega_1 - \omega_2$  are also identical in the frequency detuning range  $\Delta\omega < 100 \text{ cm}^{-1}$  for all values of  $T_0$  and  $\lambda_0$ . And only for  $\Delta\omega > 100 \text{ cm}^{-1}$ , the asymmetry appears, which increases with increasing  $\Delta\omega$  and is caused by the asymmetry of the contribution of  $\chi_{\text{nr}}$  to the total nonlinear response.

Note that this result differs from experimental data [27], according to which the dependences  $\eta(\Delta\omega)$  for the anti-Stokes and Stokes components of the nonlinear response of narrow-gap  $\text{PrBa}_2\text{Cu}_3\text{O}_{7-\delta}$  semiconductor films noticeably differ from each other already for comparatively small ( $\Delta\omega \sim 10 \text{ cm}^{-1}$ ) frequency detunings of the BP components.

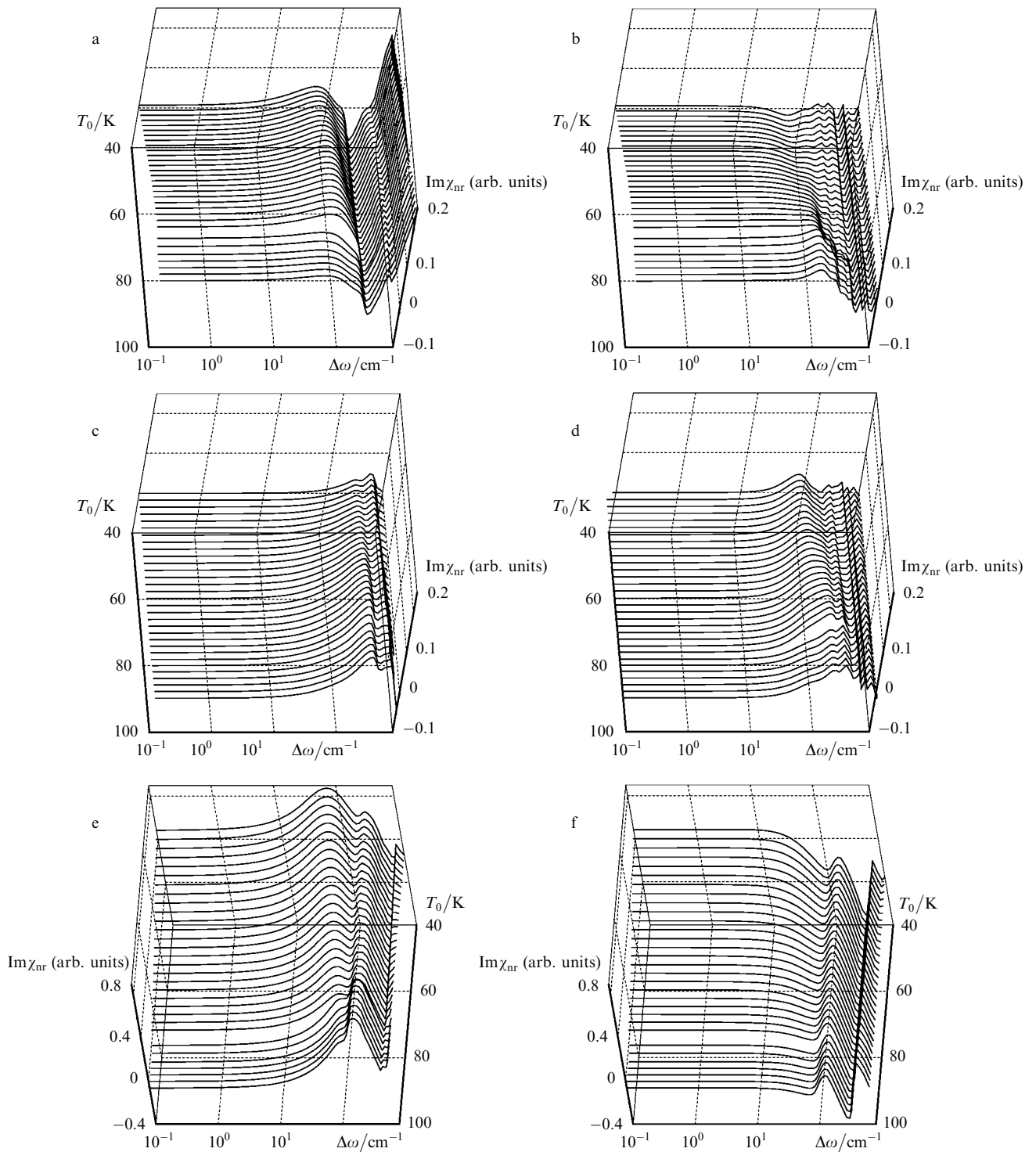


**Figure 2.** Variations in the real part  $\text{Re}\chi_{\text{nr}}$  of the nonresonance component of the total nonlinear susceptibility of a sample at frequencies  $2\omega_1 - \omega_2$  (a, c, e) and  $2\omega_2 - \omega_1$  (b, d, f) in the plane  $(\Delta\omega, T_0)$ . The point  $\Delta\omega = 0$  corresponds to  $\lambda_0 = 625$  (a, b), 630 (c, d), and 650 nm (e, f).

#### 4. Conclusions

By using the model of the HTSC nonlinear response to biharmonic pumping [4, 5] and taking into account variations in the Fermi level  $E_e^F$  and electron temperature  $T_e$  averaged over the duration of coincident pump pulses calculated in [3, 5], we have shown that the Stokes and anti-Stokes components of the HTSC nonlinear response are asymmetric. This means that for frequency detunings of the BP components  $\Delta\omega = \omega_1 - \omega_2 > 100 \text{ cm}^{-1}$ , the self-diffraction signals are generated in directions  $2\mathbf{k}_{1,2} - \mathbf{k}_{2,1}$  at

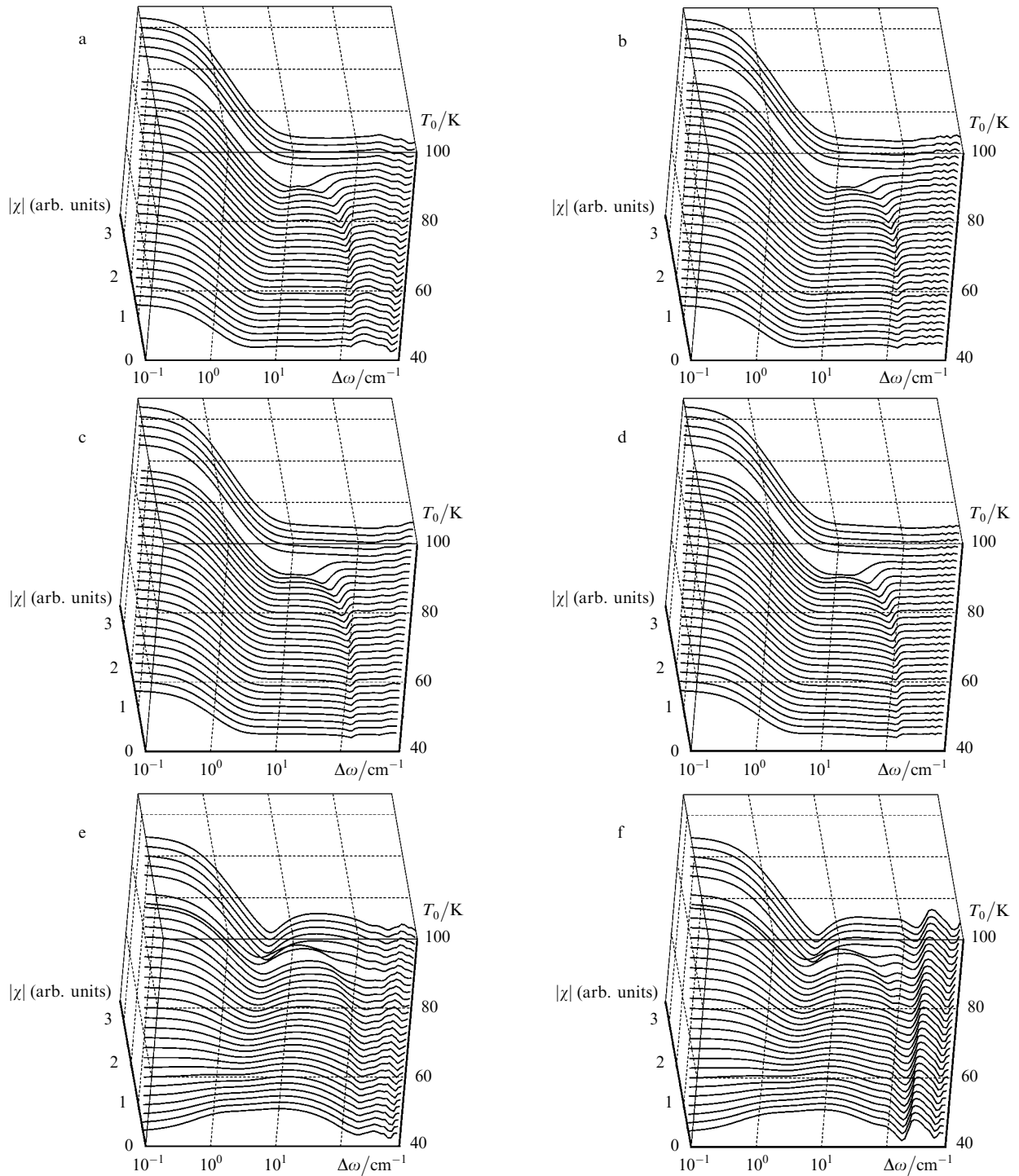
frequencies  $2\omega_{1,2} - \omega_{2,1}$  with different efficiencies  $\eta$  due to the presence of one-photon interband resonances. Nevertheless, because of the symmetry of the HTSC nonlinear response in the region of small frequency detunings ( $\Delta\omega < 100 \text{ cm}^{-1}$ ), it is possible to determine the dependence of the energy gap width  $\Delta$  in the electronic spectrum of a HTSC sample on its initial temperature  $T_0$  from the experimental dependences  $\eta(\Delta\omega, T_0)$  for the Stokes and anti-Stokes components by the presence of the characteristic two-photon resonance.



**Figure 3.** Variations in the imaginary part  $\text{Im}\chi_{\text{nr}}$  of the nonresonance component of the total nonlinear susceptibility of a sample at frequencies  $2\omega_1 - \omega_2$  (a, c, e) and  $2\omega_2 - \omega_1$  (b, d, f) in the plane  $(\Delta\omega, T_0)$ . The point  $\Delta\omega = 0$  corresponds to  $\lambda_0 = 625$  (a, b), 630 (c, d), and 650 nm (e, f).

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**Figure 4.** Variations in the modulus  $|\chi|$  of the total nonlinear susceptibility of a sample at frequencies  $2\omega_1 - \omega_2$  (a, c, e) and  $2\omega_2 - \omega_1$  (b, d, f) in the plane  $(\Delta\omega, T_0)$ . The point  $\Delta\omega = 0$  corresponds to  $\lambda_0 = 625$  (a, b), 630 (c, d), and 650 nm (e, f).

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